



**THE DATASHEET OF
WN2D201200WQ**



1. General description

Silicon Carbide Schottky diode in a 2-lead TO247-2L plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Extremely fast reverse recovery time
- Low figure of merit ($Q_C \cdot V_F$)
- Highly stable switching performance
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

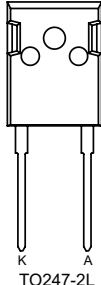

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit
Absolute maximum rating						
V_{RRM}	repetitive peak reverse voltage		1200			V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 108$ °C; Fig. 1 ; Fig. 2 ; Fig. 3	20			A
T_j	junction temperature		175			°C
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 20$ A; $T_j = 25$ °C; Fig. 5	-	1.5	1.8	V
		$I_F = 20$ A; $T_j = 150$ °C; Fig. 5	-	2.1	2.5	V
		$I_F = 20$ A; $T_j = 175$ °C; Fig. 5	-	2.25	2.8	V
Dynamic characteristics						
Q_r	recovered charge	$I_F = 20$ A; $di_F/dt = 500$ A/ μ s; $V_R = 400$ V; $T_j = 25$ °C; Fig. 7	-	39	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D201200W	TO247-2L	WNSC2D201200WQ	Tube	30	TO247L-2L	10-Nov-2020

7. Marking

Table 4. Marking codes

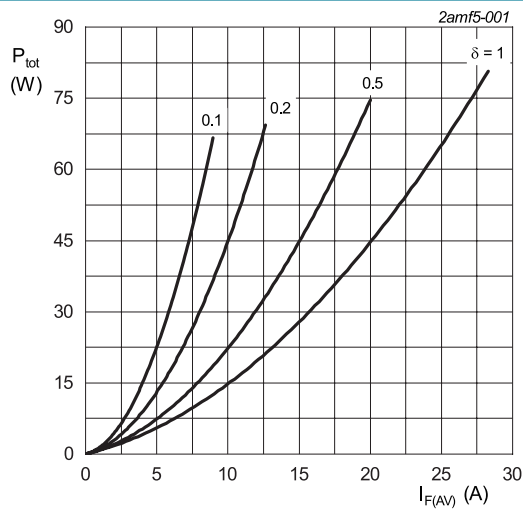
Type number	Marking codes
WNSC2D201200W	WNSC2D 201200W

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1200	V
V_{RWM}	crest working reverse voltage		1200	V
V_R	reverse voltage	DC	1200	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 108\text{ }^\circ\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3	20	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 108\text{ }^\circ\text{C}$; square-wave pulse	40	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse	125	A
		$t_p = 10\text{ }\mu\text{s}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; square-wave pulse	1150	A
I^2t	I^2t for fusing	sine-wave pulse; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; $t_p = 10\text{ ms}$	78	A^2s
T_{stg}	storage temperature		-55 to 175	$^\circ\text{C}$
T_j	junction temperature		175	$^\circ\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.728\text{ V}; R_s = 0.0751\text{ }\Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

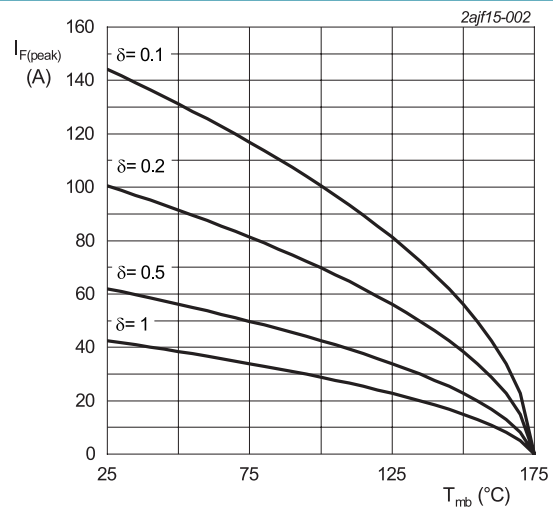


Fig. 2. Current derating as a function of mounting base temperature

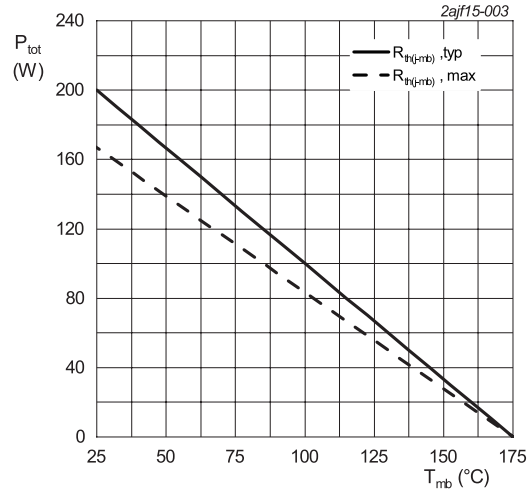


Fig. 3. Total power dissipation as a function of mounting base temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4	-	0.75	0.9	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

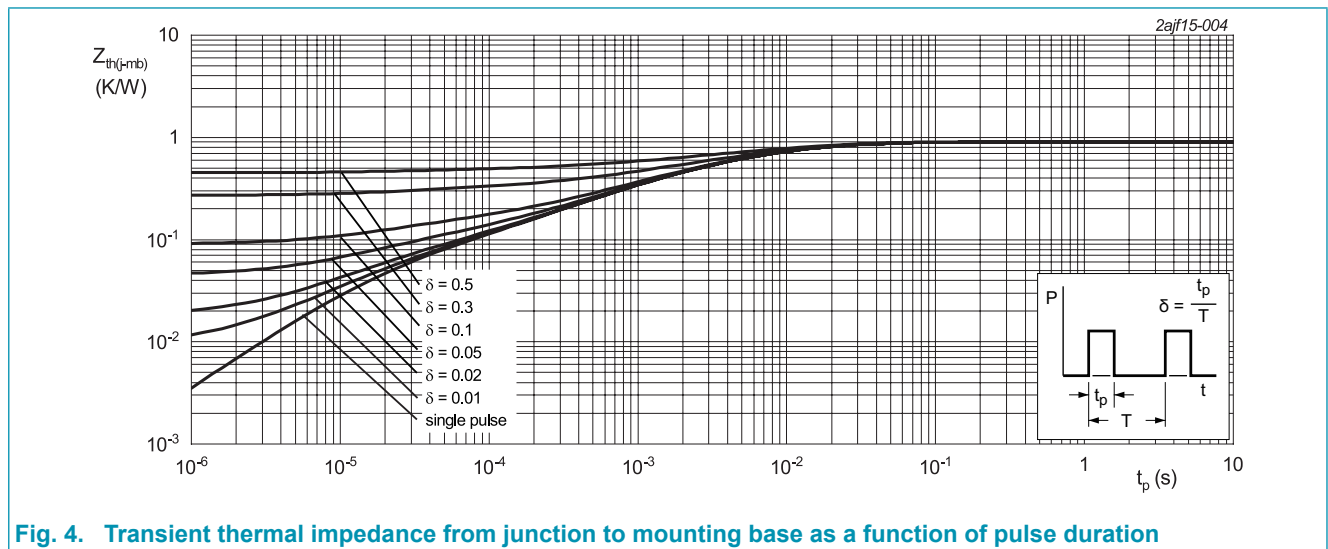
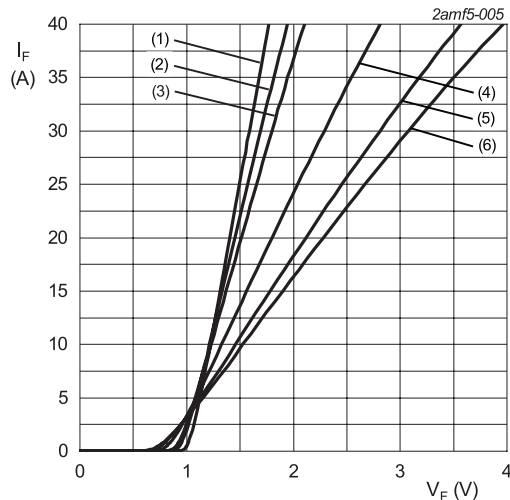


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward current	$I_F = 20\text{ A}; T_j = 25\text{ °C}; \text{Fig. 5}$	-	1.5	1.8	V
		$I_F = 20\text{ A}; T_j = 150\text{ °C}; \text{Fig. 5}$	-	2.1	2.5	V
		$I_F = 20\text{ A}; T_j = 175\text{ °C}; \text{Fig. 5}$	-	2.25	2.8	V
I_R	reverse current	$V_R = 1200\text{ V}; T_j = 25\text{ °C}; \text{Fig. 6}$	-	8	200	μA
		$V_R = 1200\text{ V}; T_j = 175\text{ °C}; \text{Fig. 6}$	-	90		μA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 20\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$	-	39	-	nC
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 1\text{ V}; T_j = 25\text{ °C}$	-	845	-	pF
		$f = 1\text{ MHz}; V_R = 400\text{ V}; T_j = 25\text{ °C}$	-	79	-	pF
		$f = 1\text{ MHz}; V_R = 800\text{ V}; T_j = 25\text{ °C}$	-	58	-	pF
E_{as}	non-repetitive avalanche energy	$I_R = 5.3\text{ A}; L = 10\text{ mH}; T_{j(\text{init})} = 25\text{ °C}$	140	-	-	mJ



$V_o = 0.728\text{ V}; R_s = 0.0751\ \Omega$
 (1) $T_j = -55\text{ °C};$ typical values
 (2) $T_j = 0\text{ °C};$ typical values
 (3) $T_j = 25\text{ °C};$ typical values
 (4) $T_j = 100\text{ °C};$ typical values
 (5) $T_j = 150\text{ °C};$ typical values
 (6) $T_j = 175\text{ °C};$ typical values

Fig. 5. Forward current as a function of forward voltage; typical values

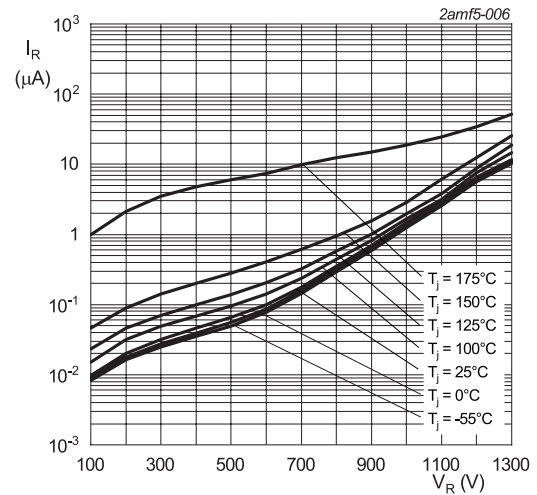


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

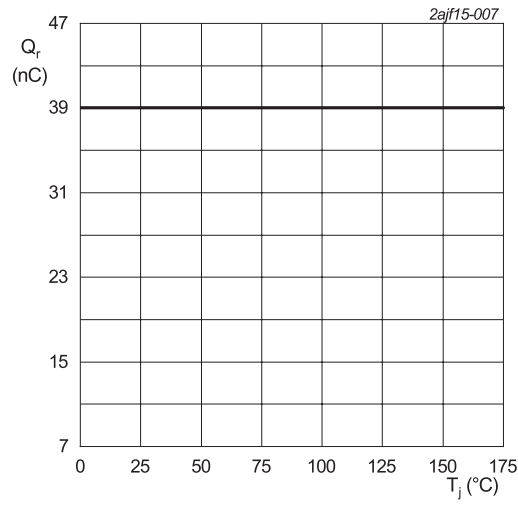
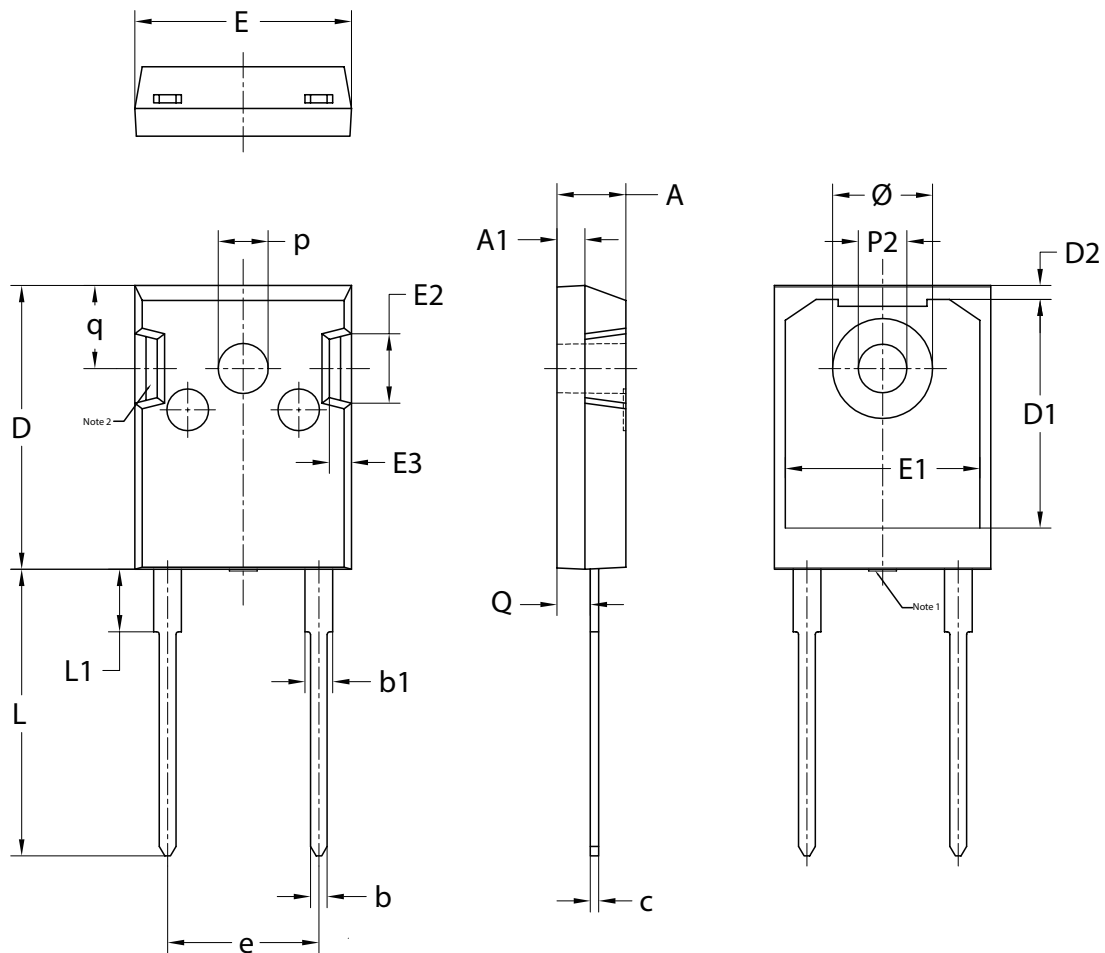


Fig. 7. Recovered charge as a function of junction temperature

11. Package outline

Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 2 leads TO-247

TO247-2L



UNIT	A	A ₁	b	b ₁	c	D	D ₁	D ₂	E	E ₁	E ₂	E ₃	e	L	L ₁	P ₂	p	Q	q	Ø
mm	5.20	2.10	1.40	2.20	0.70	20.60	16.20	1.20	15.75	14.22	5.20	1.80	10.90	20.72	4.75	3.60	3.70	2.60	6.18	7.30
	4.70	1.90	1.00	1.80	0.50	20.30	16.87	0.80	15.45	13.82	4.80	1.40	BSC	20.22	4.25	3.40	3.50	2.20	5.78	7.10

Note:

1. Mold resin protrusion max 0.127mm.
2. Metal exposed with Sn plating.

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Date of release: 12 November 2020

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